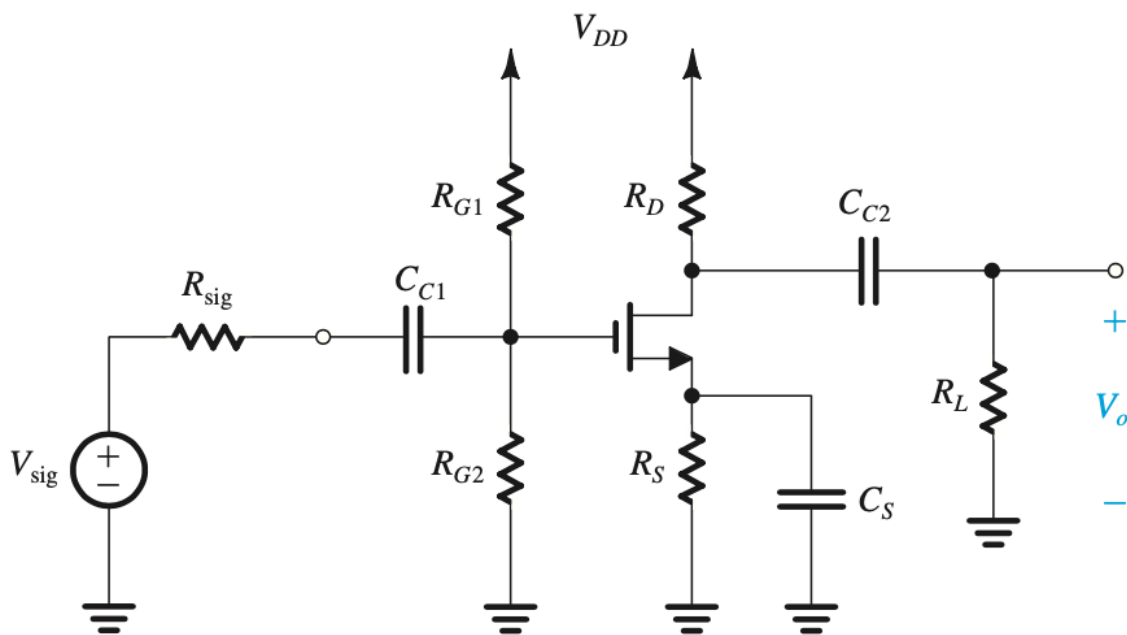


EE304 – Problem Set 2

Problem 10.4 [S&S 7/e]

10.4 The amplifier in Fig. 10.3(a) is biased to operate at $g_m = 5 \text{ mA/V}$, and has the following component values: $R_{\text{sig}} = 100 \text{ k}\Omega$, $R_{G1} = 47 \text{ M}\Omega$, $R_{G2} = 10 \text{ M}\Omega$, $C_{C1} = 0.01 \text{ }\mu\text{F}$, $R_S = 2 \text{ k}\Omega$, $C_S = 10 \text{ }\mu\text{F}$, $R_D = 4.7 \text{ k}\Omega$, $R_L = 10 \text{ k}\Omega$, and $C_{C2} = 1 \text{ }\mu\text{F}$. Find A_M , f_{P1} , f_{P2} , f_Z , f_{P3} , and f_L .



(a)

Problem 10.7 [S&S 7/e]

D 10.7 Figure P10.7 shows a current-biased CE amplifier operating at $100\ \mu\text{A}$ from $\pm 3\text{-V}$ power supplies. It employs

$R_C = 20\ \text{k}\Omega$, $R_B = 200\ \text{k}\Omega$, and operates between a $20\text{-k}\Omega$ source and a $10\text{-k}\Omega$ load. The transistor $\beta = 100$. Select C_E first, for a minimum value specified to one significant digit and providing up to 80% of f_L where f_L is to be $100\ \text{Hz}$. Then choose C_{C1} and C_{C2} , each specified to one significant digit, and each contributing about 10% of f_L . What f_L results? What total capacitance is needed?

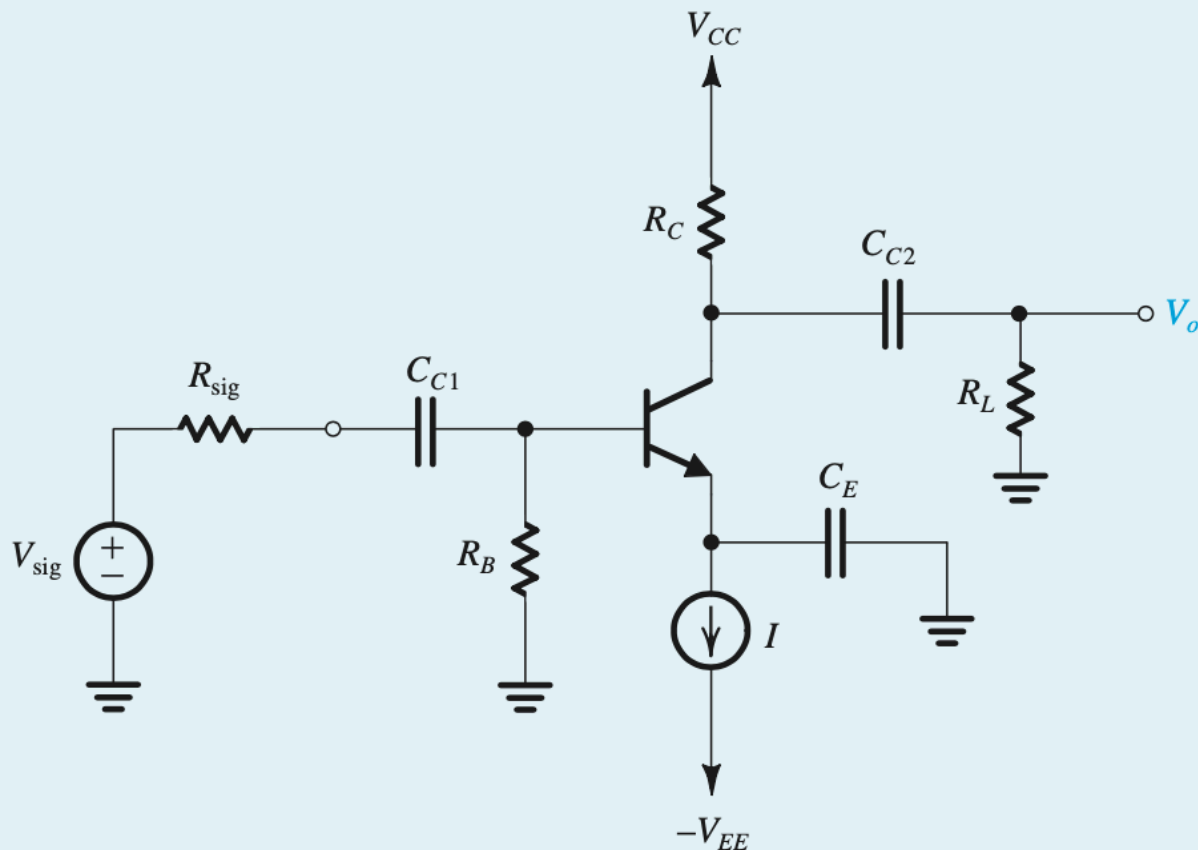


Figure P10.7

Problem 10.34 [S&S 7/e]

10.34 Consider the integrated-circuit CS amplifier in Fig. P10.34 for the case $I_{\text{BIAS}} = 100 \mu\text{A}$, Q_2 and Q_3 are matched, and $R_{\text{sig}} = 200 \text{ k}\Omega$. For Q_1 : $\mu_n C_{ox} = 90 \mu\text{A}/\text{V}^2$, $V_A = 12.8 \text{ V}$, $W/L = 100 \mu\text{m}/1.6 \mu\text{m}$, $C_{gs} = 0.2 \text{ pF}$, and $C_{gd} = 0.015 \text{ pF}$. For Q_2 : $|V_A| = 19.2 \text{ V}$. Neglecting the effect of the capacitance inevitably present at the output node, find the low-frequency gain, the 3-dB frequency f_H , and the frequency of the zero f_z .

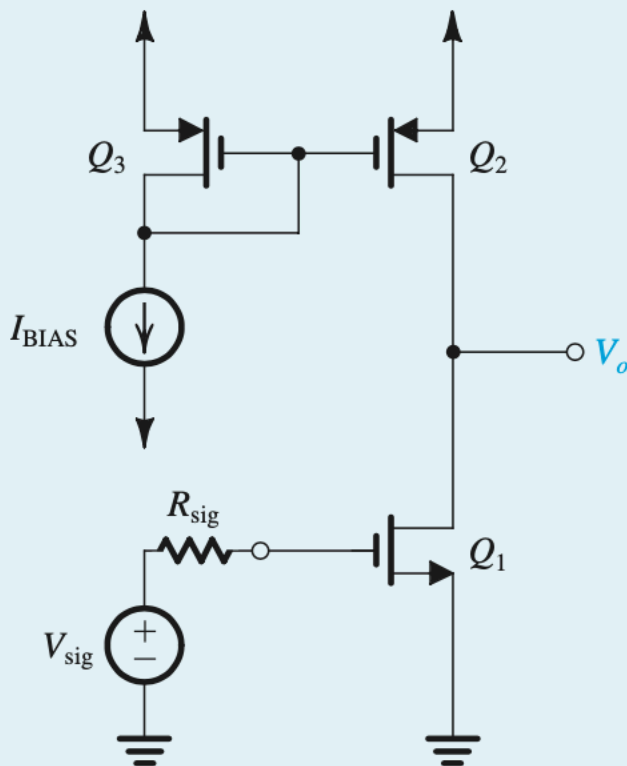


Figure P10.34

Problem 10.44 [S&S 7/e]

***10.44** The amplifier shown in Fig. P10.44 has $R_{\text{sig}} = R_L = 1 \text{ k}\Omega$, $R_C = 1 \text{ k}\Omega$, $R_B = 47 \text{ k}\Omega$, $\beta = 100$, $C_\mu = 0.8 \text{ pF}$, and $f_T = 600 \text{ MHz}$. Assume the coupling capacitors to be very large.

- Find the dc collector current of the transistor.
- Find g_m and r_π .
- Neglecting r_o , find the midband voltage gain from base to collector (neglect the effect of R_B).
- Use the gain obtained in (c) to find the component of R_{in} that arises as a result of R_B . Hence find R_{in} .
- Find the overall gain at midband.
- Find C_{in} .
- Find f_H .

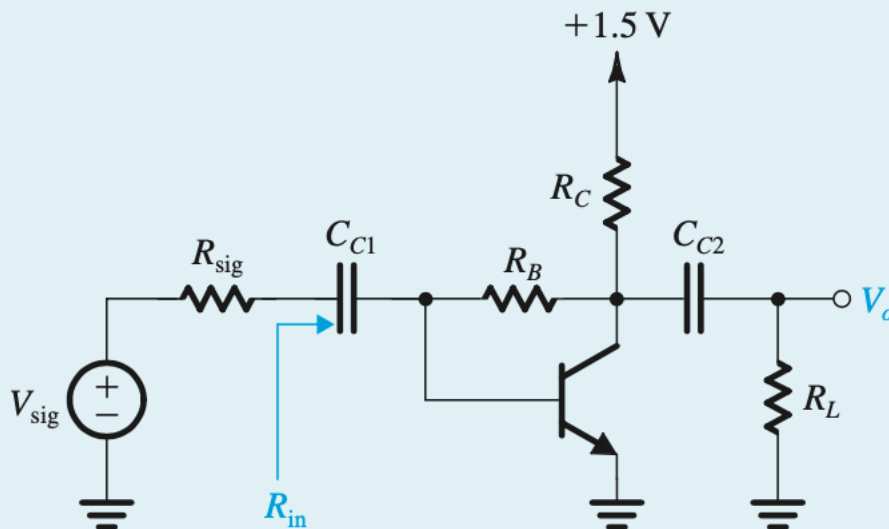


Figure P10.44